

INTERNATIONAL SEARCH REPORT

International application No.

		PCT/SE 03/0	1309		
A. CLASS	SIFICATION OF SUBJECT MATTER				
IPC7: (230B 29/36, H01L 29/12 of International Patent Classification (IPC) or to both na	ational classification an	d IPC		
	S SEARCHED				
Minimum d	ocumentation searched (classification system followed by	y classification symbol	s)		
IPC7: H	101L, C30B				
	ion searched other than minimum documentation to the	extent that such docu	ments are included in	n the fields searched	
	TI,NO classes as above				
Electronic d	ata base consulted during the international search (name	e of data base and, whe	ere practicable, search	h terms used)	
EPO-INI	FERNAL, WPI DATA, INSPEC				
	MENTS CONSIDERED TO BE RELEVANT		,		
Category*	Citation of document, with indication, where app	propriate, of the rele	vant passages	Relevant to claim No.	
A	Akira Itoh et al			1-31	
٨	Christal Reviews in Solid St Sciences, 22(2):111-197	ate and Mater	ials	1 31	
	Singel Crystal Growth of SIC	and Electron	ic		
	Devices see whole document				
					
A	US 6030661 A (OLLE KORDINA ET AL 29 February 2000 (29.02.00)	.),		1-31	
Α	J.R. Jenny et al			1-31	
	Optical and electrical chara inpurities in silicon carbic				
	vapor transport				
	J. Appl. Phys 79 (5) 1 march	1 1996			
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X Furth	er documents are listed in the continuation of Box	C. X See p	atent family annex	ι.	
"A" docume	categories of cited documents: mt defining the general state of the art which is not considered [particular relevance]	date and not in	t published after the into a conflict with the appli r theory underlying the	ernational filing date or priority cation but cited to understand invention	
"E" earlier a	application or patent but published on or after the international	considered nov	el or cannot be conside	claimed invention cannot be tred to involve an inventive	
cited to special	establish the publication date of another citation or other reason (as specified) ant referring to an oral disclosure, use, exhibition or other	"Y" document of particular relevance: the claimed invention cannot be considered to involve an inventive step when the document is			
means "P" docume	nt published prior to the international filing date but later than	combined with being obvious	one or more other such to a person skilled in the other of the same patent	n documents, such combination le art	
	e actual completion of the international search	Date of mailing of	the international s		
3 Novem	mber 2003	U	7 -11- 2003		
Name and	mailing address of the ISA/	Authorized officer			
	Patent Office S-102 42 STOCKHOLM	Daniel Moe/MN			
		Daniel Fide/Fin			

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INTERNATIONAL SEARCH REPORT

International application No. PCT/SE 03/01309

		01309		
C (Continua	ation). DOCUMENTS CONSIDERED TO BE RELEVANT			
Category*	Citation of document, with indication, where appropriate, of the rele	vant passages	Relevant to claim No	
A	M. Trivedi et al Dept. of Elec. Engg. & Comp.Sci University of Illinois at Chicaga IEEE 1998 Hight Temperature Performance Limits of IGBT Modules		1-31	
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INTERNATIONAL SEARCH REPORT

Information on patent family members

06/09/03

International application No.
PCT/SF 03/01309

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Patent document cited in search report			Publication date	Patent family member(s)		Publication date	
US	6030661	Α	29/02/00	NONE	·- ·-		
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